

## TO-220FI( LS )( Full Isolation ) Outline Series

Sanyo's new outline TO-220FI(Full isolation : perfect isolation type) has a wide variety of products.

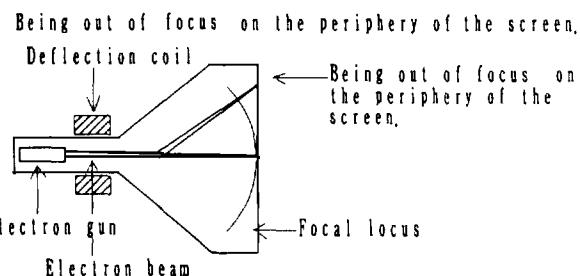
**dc Dynamic focus transistors**

These products are fabricated by Sanyo's original high technology.

\* High voltage amplifying, high voltage switching and high withstand voltage.

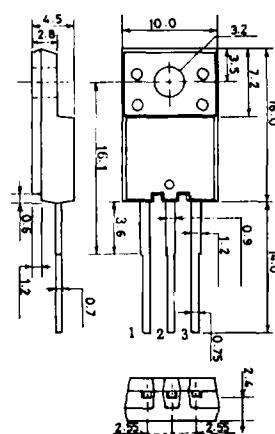
\* High frequency operation.

A spot size of an electron beam is always kept constant all over the CRT screen by changing a focus of a CRT's electron beam while scanning horizontally and vertically. This eliminates being out of focus of the screen and gives you a very clear image. Thus this technology is indispensable for high definition displays.



Type No.	Absolute Maximum Ratings/Ta=25°C				Electrical Characteristics/Ta=25°C							
	V <sub>CBO</sub> (V)	V <sub>CEO</sub> (V)	I <sub>C</sub> (mA)	P <sub>C</sub> (W)	V <sub>CE</sub> (V)	I <sub>C</sub> (mA)	h <sub>FE</sub>	I <sub>C</sub> (mA)	I <sub>B</sub> (mA)	V <sub>CE(sat)</sub> max (V)	V <sub>CB</sub>	cob typ (pF)
2SC4630LS	1500	900	100	2	5	10	min30	20	4	5	100	2.8
2SC4631LS	1500	900	300			30	min30	60	12			5.0
2SC4632LS	1500	1200	10			0.5	10 ~ 60	1	0.2			1.6
2SC4633LS	1500	1200	30			1.5	10 ~ 60	3	0.6			2.0
2SC4634LS	1500	1500	10			0.2	10 ~ 60	0.5	0.1			1.5
2SC4635LS	1500	1500	20			0.6	10 ~ 60	1.5	0.3			1.9
2SC4636LS	2000	1800	10			0.1	10 ~ 60	0.2	0.04			1.4
2SC4637LS	2000	1800	15			0.3	10 ~ 60	0.6	0.12			1.8
2SC4710LS	2100	2100	10			0.5	10 ~ 60	1	0.2			1.3
2SC4887LS	2500	1200	100			5	10 ~ 60	20	4			2.5
2SC4888LS	2500	1200	300			20	10 ~ 60	60	12			4.0

Case Outline (unit: mm)



1:Base, 2:Collector, 3:Emitter  
1:Gate, 2:Drain, 3:Source

**dc Power MOS FET \*PD : Tc = 25°C**

Available for switching regulators, DC-DC converters and driving motors .

Features \* Low ON resistance, low loss and fast switching operation.

\* Very high withstand voltage, fast switching operation and low capacitance.

\*RDS(on):VGS=10V

Type No.	Absolute Maximum Ratings/Ta=25°C					Electrical Characteristics /Ta=25°C		
	V <sub>DSS</sub> (V)	V <sub>GS</sub> (V)	I <sub>D</sub> (A)	I <sub>DP</sub> (A)	*P <sub>D</sub> (W)	V <sub>GS(off)</sub> (V)	*R <sub>DS(on)</sub> typ/max(Ω)	C <sub>iss</sub> typ (pF)
2SK1412LS	1500	±20	0.1	0.2	20	2~3	140/200	40
2SK1443LS			1	4	20		3.5/4.5	250
2SK1444LS			3	12	25		2/2.6	400
2SK1445LS			5	20	30		1/1.4	700
2SK1446LS			7	28	35		0.6/0.8	1200
2SK1447LS			9	36	40		0.47/0.6	1600
2SK1458LS	900	±30	0.1	0.2	20		50/70	45
2SK1459LS			2.5	5	30		4.7/6	350
2SK1460LS			3.5	7	40		2.8/3.6	700
2SK2043LS	600	±30	2	8	25	2~3	3.2/4.3	400
2SK2044LS			4	16	30		1.8/2.4	700
2SK2045LS			5.5	22	35		1.1/1.5	1100

Precaution: Be careful not to destroy MOS type transistors because they cannot withstand much static electricity.

These specifications are subject to change without notice.